

SINGLE LOW VOLTAGE RAIL-TO-RAIL **OUTPUT OPERATIONAL AMPLIFIER**

Description

The AZV321 is single low voltage (2.7V to 5.5V) operational amplifier which has rail-to-rail output swing capability. The input common-mode voltage range includes ground. The chip exhibits excellent speedpower ratio, achieving 1MHz of bandwidth and 1V/µs of slew rate with low supply current.

The AZV321 is built with BiCMOS process. It has bipolar input and output stages for improved noise performance, low input offset and higher output current drive.

The AZV321 is available in the package of SC-70-5, which is approximately half the size of SOT-23-5. The small package saves space on pc boards, and enables the design of small portable electronic devices. It also allows the designer to place the device closer to the signal source to reduce noise pickup and increase signal integrity.

The AZV321 is also available in standard SOT-23-5 package.

Features (For V_{CC} =5V and V_{EE} =0V, Typical unless Otherwise Noted)

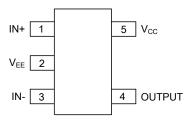
- Guaranteed 2.7V to 5.5V Performance
- No Crossover Distortion
- Gain-Bandwidth Product 1MHz
- Industrial Temperature Range: -40°C to +85°C
- Low Supply Current: 130µA
- Rail-to-Rail Output Swing under 10kΩ Load:

V_{OH} up to V_{CC}-10mV V_{OL} near to V_{EE} +65mV

 V_{CM} : -0.1V to V_{CC} -0.8V

Pin Assignments

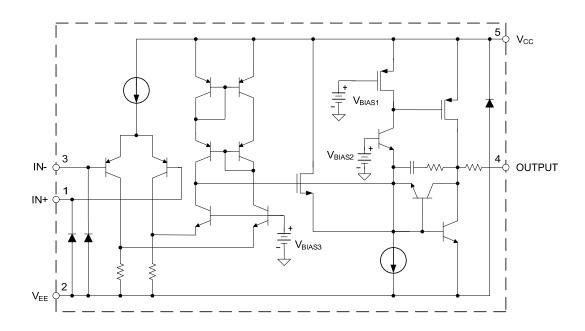
KS/K Package (SC-70-5/SOT-23-5)



Applications

- Active Filters
- Low Power, Low Voltage Applications
- General Purpose Portable Devices
- Cellular Phone, Cordless Phone
- Battery-Powered Systems

Functional Block Diagram







AZV321

Absolute Maximum Ratings (Note 1)

Symbol	Parameter	Rating	Unit
V _{CC}	Power Supply Voltage	6	V
T _J	Operation Junction Temperature	150	°C
T _{STG}	Storage Temperature Range	-65 to 150	°C
T _{LEAD}	Lead Temperature (Soldering, 10 Seconds)	260	°C
	ESD (Machine Model)	200	V
	ESD (Human Body Model)	2000	V

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Unit
V _{CC}	Supply Voltage	2.7	5.5	V
T _A	Ambient Operating Temperature Range	-40	85	°C





AZV321

Electrical Characteristics

AZV321-2.7V Electrical Characteristics (All limits are guaranteed for T_A =25°C, V_{CC} =2.7V, V_{EE} =0V, V_{CM} =1.0V, V_O = V_{CC} /2 and R_L >1M Ω , limits in **bold types** are guaranteed for T_A =-40°C to 85°C, unless otherwise specified. Note 2)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
\/	Input Offset Voltage			1.7	7	m\/
V _{IO}	Input Offset Voltage				9	mV
1	January Dina Comment			11	250	^
l _Β	Input Bias Current				500	nA
1	Input Offset Current			5	50	nA
I _{IO}	Input Offset Current				150	IIA
V _{CM}	Input Common Mode Voltage Range	for CMRR≥50dB	-0.1		1.9	V
,	Supply Current	V _O =V _{CC} /2, A _{VCL} =1, no load		80	170	μΑ
I _{CC}					270	
CMRR	Common Mode Rejection Ratio	0≤V _{CM} ≤1.7V	50	65		dB
PSRR	Power Supply Rejection Ratio	2.7V≤V _{CC} ≤5V, V _O =1V	50	60		dB
I _{SOURCE}	Outside Object Circuit Comment	V _O =0V	5	20		mA
I _{SINK}	Output Short Circuit Current	V _O =2.7V	10	30		mA
V _{OH}	Outrot Valta na Outra	D 401-0 t- 4.051/	2.60	2.69		V
V _{OL}	Output Voltage Swing	R_L =10kΩ to 1.35V		60	180	mV
GBWP	Gain Bandwidth Product	C _L =200pF		1		MHz
фм	Phase Margin			60		Deg
G _M	Gain Margin			10		dB

Note 2: Limits over the full temperature are guaranteed by design, but not tested in production.



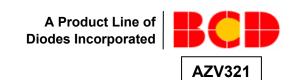
Electrical Characteristics (Cont.)

AZV321-5V Electrical Characteristics (All limits are guaranteed for T_A =25°C, V_{CC} =5V, V_{EE} =0V, V_{CM} =2.0V, V_O = V_{CC} /2 and R_L >1M Ω , limits in **bold types** are guaranteed for T_A =-40°C to 85°C, unless otherwise specified. Note 2)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
1/	Innut Officet Voltage			1.7	7	
V_{IO}	Input Offset Voltage				9	mV
1	Input Ding Current			11	250	nA
l _Β	Input Bias Current				500	
I _{IO}	Input Offset Current			5	50	nA
IIO	·				150	ПА
V_{CM}	Input Common Mode Voltage Range	for CMRR≥50dB	-0.1		4.2	V
laa	Supply Current	V _O =V _{CC} /2, A _{VCL} =1, no load		130	250	^
Icc	Supply Current	V0-VCC/2, AVCL-1, 110 10au			350	μA
Gv	Lorgo Signal Voltago Cain	R _L =2kΩ	84	100		dB
9	Large Signal Voltage Gain	KL-2K11	80			uБ
CMRR	Common Mode Rejection Ratio	0≤V _{CM} ≤4V	50	65		dB
PSRR	Power Supply Rejection Ratio	2.7V≤V _{CC} ≤5V, V _O =1V, V _{CM} =1V	50	60		dB
I _{SOURCE}	Output Short Circuit Current	V _O =0V	5	60		mA
I _{SINK}	Output Short Circuit Current	V _O =5V	10	160		mA
		R_L =2k Ω to 2.5V	4.7	4.96		- V
V_OH			4.6			
VOH		R_L =10k Ω to 2.5V	4.9	4.99		
	Output Voltage Swing	N10K22 (0 2.5V	4.8			
	Output Voltage Owing	R _L =2kΩ to 2.5V		120	300	
V_{OL}					400	mV
VOL				65	180	1117
		R_L =10k Ω to 2.5V			280	
SR	Slew Rate			1		V/µS
GBWP	Gain Bandwidth Product	C _L =200pF		1		MHz
φм	Phase Margin			60		Deg
G_M	Gain Margin			10		dB

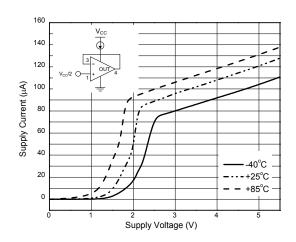
Note 2: Limits over the full temperature are guaranteed by design, but not tested in production.



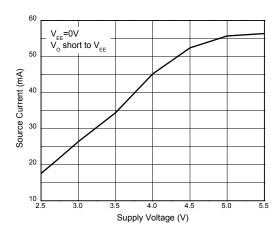


Performance Characteristics

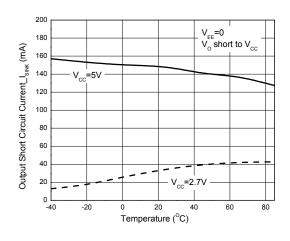
Supply Current vs. Supply Voltage



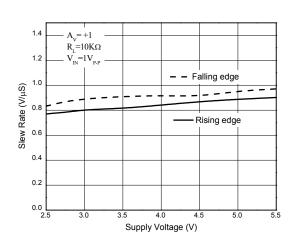
Output Source Current vs. Supply Voltage



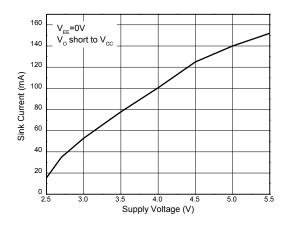
Short Circuit Current $_{I_{SINK}}$ vs. Temperature



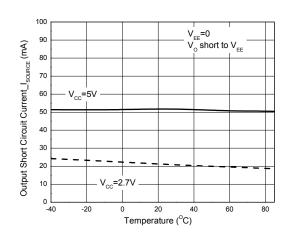
Slew Rate vs. Supply Voltage



Output Sink Current vs. Supply Voltage



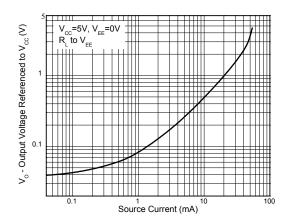
Short Circuit Current_ I_{SOURCE} vs. Temperature



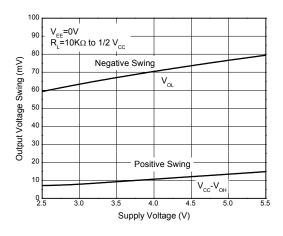


Performance Characteristics (Cont.)

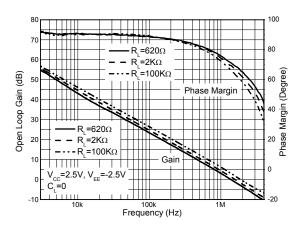
Output Voltage vs. Source Current



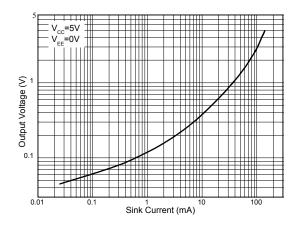
Output Voltage Swing vs. Supply Voltage



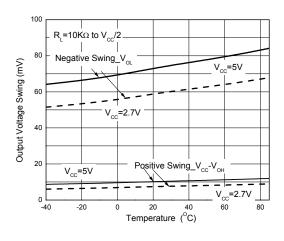
Gain and Phase vs. Frequency and Resistive Load



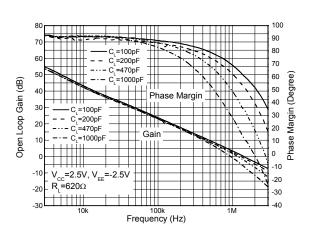
Output Voltage vs. Sink Current



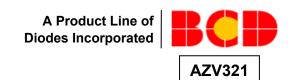
Output Voltage Swing vs. Temperature



Gain and Phase vs. Frequency and Capacitive Load

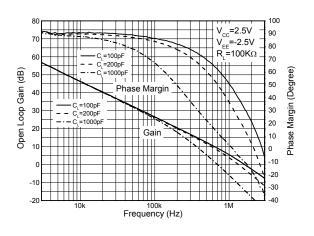




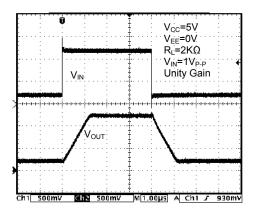


Performance Characteristics (Cont.)

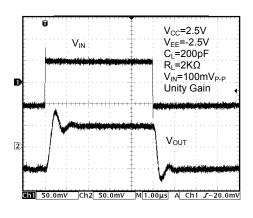
Gain and Phase vs. Frequency and Capacitive Load



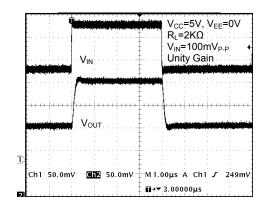
Non-Inverting Input Large Signal Pulse Response



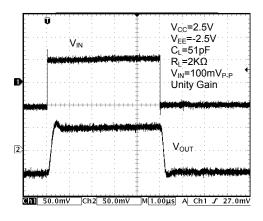
Output with Excessive Capacitive Load



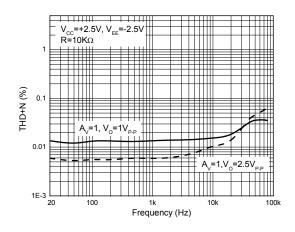
Non-Inverting Input Small Signal Pulse Response



Output with Excessive Capacitive Load

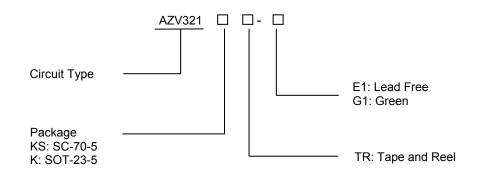


THD+N vs. Frequency





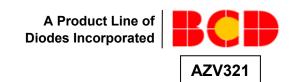
Ordering Information



Dardinana	Temperature	Part Number		Marking ID		Daaking Tura
Package	Range	Lead Free	Green	Lead Free Green		Packing Type
SC-70-5	40 to 0500	AZV321KSTR-E1	AZV321KSTR-G1	21	B1	Tape & Reel
SOT-23-5	-40 to 85°C	AZV321KTR-E1	AZV321KTR-G1	E6D	G6D	Tape & Reel

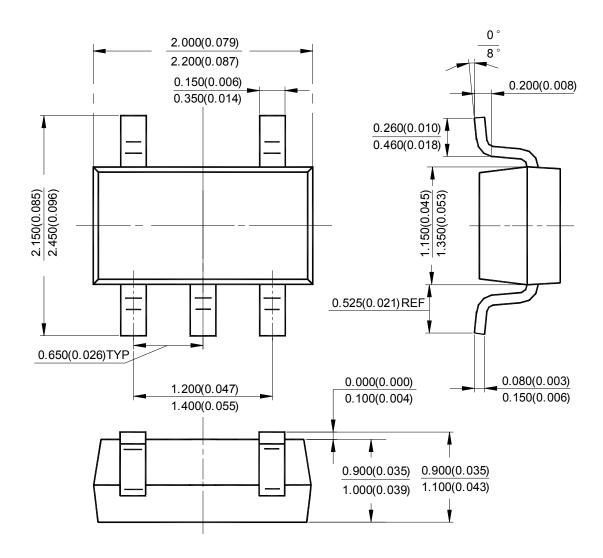
BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant. Products with "G1" suffix are available in green packages.





Package Outline Dimensions (All dimensions in mm(inch).)

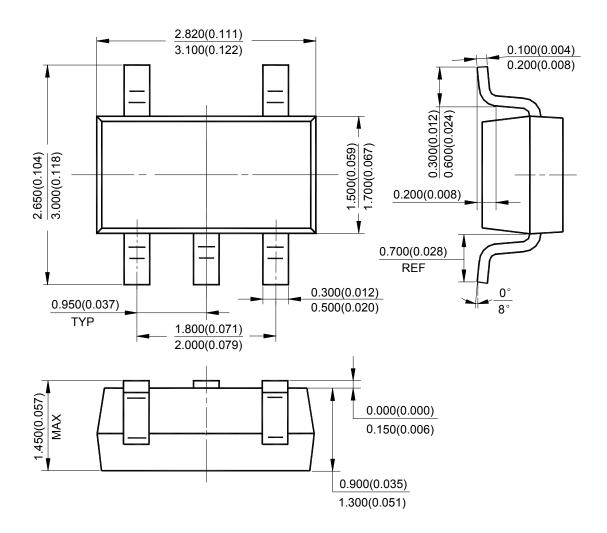
SC-70-5





Package Outline Dimensions (Cont. All dimensions in mm(inch).)

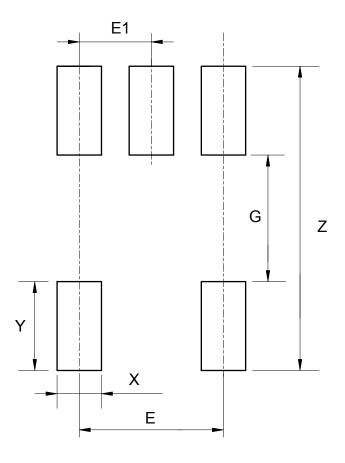
SOT-23-5





Suggested Pad Layout

SC-70-5

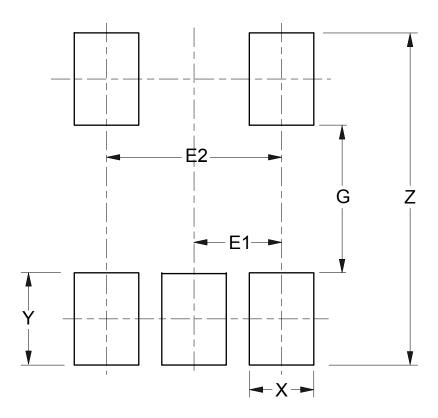


Dimongions	Z	G	X	Y	Е	E1
Dimensions	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)
Value	2.740/0.108	1.140/0.045	0.400/0.016	0.800/0.031	1.300/0.051	0.650/0.026



Suggested Pad Layout (Cont.)

SOT-23-5



Dimensions	Z	G	X	Y	E1	E2
Dimensions	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)
Value	3.600/0.142	1.600/0.063	0.700/0.028	1.000/0.039	0.950/0.037	1.900/0.075



AZV321

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